

FORM PTO-1449  
(REV. 7-80)U.S. DEPARTMENT OF COMMERCE  
PATENT AND TRADEMARK OFFICE

ATTY. DOCKET NO.: ST9903a

SERIAL NO. 09/890,656

## LIST OF REFERENCES CITED BY APPLICANT

(Use several sheets if necessary)

APPLICANT: Reinhard Schauer et al.

FILING DATE: August 2, 2001

GROUP: 2811

## U.S. PATENT DOCUMENTS

EXAMINER INITIAL		DOCUMENT NUMBER	DATE	NAME	CLASS	SUBCLASS	FILING DATE IF APPROPRIATE
	AA						
	AB						
	AC						
	AD						
	AE						
	AF						
	AG						
	AH						
	AI						
	AJ						
	AK						

## FOREIGN PATENT DOCUMENTS

		DOCUMENT NUMBER	DATE	COUNTRY	CLASS	SUBCLASS	TRANSLATION	
							YES	NO
	AL							
	AM							
	AN							
	AO							
	AP							

## OTHER REFERENCES (Including Author, Title, Date, Pertinent Pages, Etc.)

TT	AR		SZE, S.M.: Physics of Semiconductor Devices, New York, Wiley, 1969, p. 43
TT	AS		Ohshita, Y. et al; Journal of Crystal Growth, 1991, vol. 108, pp. 499-507
TT	AT		Hammond, M.L.: Silicon Epitaxy, Solid State Technology, 1978, H. 11, pp. 68-75

EXAMINER

Thim [signature]

DATE CONSIDERED

01-08-03

EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 608; draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.